

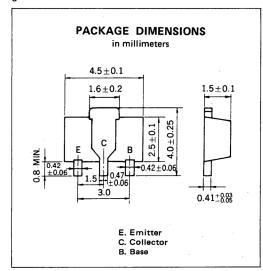
2SB1115, 1115A

2SR1115 2SR1115A

PNP SILICON EPITAXIAL TRANSISTOR POWER MINI MOLD

DESCRIPTION

2SB1115, 1115A are designed for audio frequency power amplifier and switching application, especially in Hybrid Integrated Circuits.



FEATURES

- Low $V_{CE(sat)}$. $V_{CE(sat)} = -0.2 \text{ V}$ at 1 A
- Complement to 2SD1615, 1615A

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C)

		2301113	2001110/	~
Collector to Base Voltage	V_{CBO}	-60	-80	· V
Collector to Emitter Voltage	V_{CEO}	50	-60	V
Emitter to Base Voltage	V_{EBO}	-6.	0	· V
Collector Current (DC)	Ic (DC)	-1.	0	Α
Collector Current (Pulse)*	I _{C (Pulse)}	-2.	0	Α
Total Power Dissipation **	P_{T}	2.	0	W
Junction Temperature	T_i	15	. 0	°C
Storage Temperature Range	$T_{stg^{'}}$	-55 to +150		°C

^{*}PW \leq 10 ms, Duty Cycle \leq 50 %

ELECTRICAL CHARACTERISTICS (TA = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Collector Cutoff Current	ІСВО			-100	nA	2SB1115	V _{CB} = -60 V, I _E = 0
				-100	nA	2SB1115A	V _{CB} = -80 V, I _E = 0
Emitter Cutoff Current	IEBO			-100	nA	V _{EB} = -6.0 V, I _C = 0	
DC Current Gain	h _{FE1} ***	135	340	600		2SB1115	V _{CF} = -2.0 V, I _C = -100 mA
		135		400		2SB1115A	VCE2.0 V, 1C 100 IIIA
DC Current Gain	hFE2 ***	100	200			$V_{CE} = -2.0 \text{ V}, I_{C} = -1.0 \text{ A}$	
Collector Saturation Voltage	V _{CE(sat)} ***		-0.2	-0.3	V	$I_C = -1.0 \text{ A}, I_B = -50 \text{ mA}$	
Base Saturation Voltage	VBE(sat)***		-0.9	-1.2	V	I _C = -1.0 A, I _B = -50 mA	
Base to Emitter Voltage	V _{BE} ***	-600		-700	mV	$V_{CE} = -2.0 \text{ V, } I_{C} = -50 \text{ mA}$	
Gain Bandwidth Product	fT	80	120		MHz	V _{CE} = -2.0 V, I _E = -100 mA	
Output Capacitance	C _{ob}		25		pF	V _{CB} = -10 V, I _E = 0, f = 1.0 MHz	

^{***}Pulsed: PW \leq 350 μ s, Duty Cycle \leq 2 %

$h_{\text{FE}} \ Classification$

- · · -					
MARKING	2SB1115	YM	YL	YK	
	2SB1115A	YQ	YP		
hFE1		135 to 270	200 to 400	300 to 600	

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version. Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.

^{**}When mounted on ceramic substrate of 16 cm² x 0.7 mm

TYPICAL CHARACTERISTICS (TA = 25°C)

